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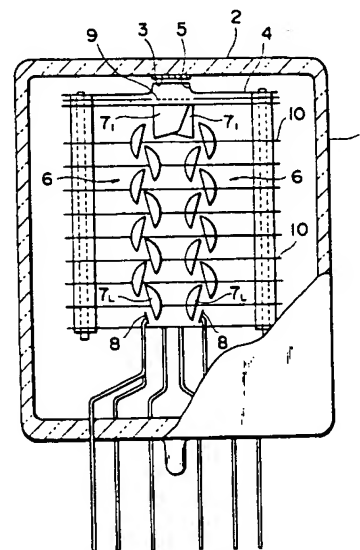
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54 **Photomultiplier and electron multiplier.**

57 The present invention relates to a linear multi-anode photomultiplier or electron multiplier on which a plurality of light beams to be measured or energy beams of electrons, ions and so forth are incident one-dimensionally. The object of the present invention is to prevent crosstalk between dynode arrays caused by leaking electrons. A transmission type photomultiplier is characterized in that the direction of secondary electron emission of the first-stage dynode of each dynode array is set in the opposite direction at 180° from that of an adjacent dynode array. Then, adjacent dynode arrays will not oppose each other but are shifted from each other at a predetermined distance in the lateral direction. Accordingly, even if electrons leak from a gap between dynodes of a certain dynode array, the leaking electrons will not enter the adjacent dynode array, thereby preventing crosstalk.

Fig. 4



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BACKGROUND OF THE INVENTIONField of the Invention

5 The present invention relates to a photomultiplier or an electron multiplier having dynode arrays for multiplying electrons by the secondary electron emission effect and, more particularly, to a so-called linear multi-anode photomultiplier and electron multiplier in which portions thereof, on which a plurality of light beams to be measured or energy beams of electrons, ions and so force are incident, are aligned one-dimensionally.

10 Related Background Art

Figs. 1, 2 and 3 show an example of a conventional linear multi-anode photomultiplier. This photomultiplier is a head-on type photomultiplier in which incident window 2 for receiving light beams to be measured are formed on one end face of a glass bulb 1. Transmission type photoelectric surfaces 3 for converting the incident  
15 light to be measured to photoelectrons are formed on the inner surface of the incident window 2 in a one-dimensional array. One focusing electrode 4 is arranged inside the glass bulb 1 to be parallel to the incident window 2, and openings 5 are formed in a one-dimensional array at a portion of the focusing electrode 4 opposing the photoelectric surfaces 3. When a plurality of light beams to be measured are incident on the respective photoelectric surfaces 3 to generate photoelectrons, the photoelectrons are guided to corresponding  
20 dynode arrays 6 through the openings 5. The dynode arrays 6 of the photomultiplier shown in Fig. 1 have in-line dynode structure. The photoelectrons are multiplied by the secondary electron emission effect in each stage of dynode 7 of the respective dynode arrays 6, and the multiplied photoelectrons are finally captured by anodes 8 as output signals.

In the conventional photomultiplier described above, some of leaking electrons from the gaps among the  
25 dynodes 7 of each dynode array 6 enter the gaps among the dynodes 7 of an adjacent dynode array 6 to cause so-called crosstalk. Crosstalk impairs independency of each dynode array 6 and degrades the detection precision of the light beams to be measured.

The photomultiplier described above is a transmission type photomultiplier having photoelectric surfaces on the inner surface of the incident window. A reflection type photomultiplier has a similar problem of crosstalk.

30 An electron multiplier for detecting the energy beams of electrons, ions and so force also has a problem of crosstalk since its dynode array has a substantially same arrangement.

SUMMARY OF THE INVENTION

35 It is, therefore, an object of the present invention to provide a linear multi-anode type photomultiplier and electron multiplier that can prevent crosstalk between dynode arrays caused by leaking electrons.

The above object and other objects will be further apparent from the following description.

Provided according to the present invention is a photomultiplier comprising a transparent sealed container having, on one end face thereof, incident window on which light to be measured is incident, first and second  
40 transmission type photoelectric surfaces formed on an inner surface of said incident window, and first and second dynode arrays having a plurality of stages of dynodes for multiplying photoelectrons supplied from said first and second transmission type photoelectric surfaces respectively, photoelectron incident ports of first-stage dynodes of said first and second dynode arrays opposing said first and second transmission type photoelectric surfaces respectively, wherein said dynodes of said first and second dynode arrays are arranged  
45 such that electrons leaking from said first dynode array will not enter said second dynode array.

Also provided according to the present invention is a photomultiplier comprising a transparent sealed container having, on one end face thereof, incident window on which light to be measured is incident, first and second reflection type photoelectric surfaces arranged in said sealed container and having light beam incident  
50 ports arranged to oppose said incident window, and first and second dynode arrays having a plurality of stages of dynodes for multiplying photoelectrons supplied from said first and second reflection type photoelectric surfaces respectively, said first and second dynode arrays being provided to correspond to said first and second reflection type photoelectric surfaces, wherein said dynodes of said first and second dynode arrays are arranged such that electrons leaking from said first dynode array will not enter said second dynode array.

55 Further provided according to the present invention is an electron multiplier comprising first and second dynode arrays having a plurality of stages of dynodes for multiplying electrons generated when energy beams of electrons, ions and so force are incident thereon, said plurality of stages of dynodes including first-stage dynodes arranged such that energy beam incident ports thereof are directed in a direction along which said energy beams are incident, wherein said dynodes of said first and second dynode arrays are arranged such

that electrons leaking from said first dynode array will not enter said second dynode array.

The present invention will become more fully understood from the detailed description given hereinbelow and the accompanying drawings which are given by way of illustration only, and thus are not to be considered as limiting the present invention.

5 Further scope of applicability of the present invention will become apparent from the detailed description given hereinafter. However, it should be understood that the detailed description and specific examples, while indicating preferred embodiments of the invention, are given by way of illustration only, since various changes and modifications within the spirit and scope of the invention will become apparent to those skilled in the art from this detailed description.

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#### BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 is a longitudinal sectional view showing a conventional transmission type linear multi-anode photomultiplier.

15 Fig. 2 is a plan view of the photomultiplier of Fig. 1.

Fig. 3 is a perspective view showing the arrangement of dynode arrays used in the photomultiplier of Fig. 1.

Fig. 4 is a longitudinal sectional view showing an embodiment of a transmission type linear multi-anode photomultiplier according to the present invention.

20 Fig. 5 is a plan view of the photomultiplier of Fig. 4.

Fig. 6 is a perspective view showing the arrangement of dynode arrays used in the photomultiplier of Fig. 4.

Fig. 7 is a longitudinal sectional view showing another embodiment of a transmission type linear multi-anode photomultiplier according to the present invention.

25 Fig. 8 is a longitudinal sectional view showing still another embodiment of a transmission type linear multi-anode photomultiplier according to the present invention.

Fig. 9 is a perspective view showing the arrangement of dynode arrays used in the photomultiplier of Fig. 8.

30 Fig. 10 is a longitudinal sectional view showing an embodiment of a reflection type linear multi-anode photomultiplier according to the present invention.

Fig. 11 is a longitudinal sectional view showing another embodiment of a reflection type linear multi-anode photomultiplier according to the present invention.

Fig. 12 is a longitudinal sectional view showing an embodiment of a linear multi-anode electron multiplier according to the present invention.

35

#### DESCRIPTION OF THE PREFERRED EMBODIMENTS

##### (Embodiment 1)

40 The preferred embodiments of the present invention will be described in detail with reference to the accompanying drawings. Note that the same or corresponding portions as in the conventional structures described above are denoted by the same reference numerals.

Figs. 4 and 5 show a transmission type linear multi-anode photomultiplier according to a preferred embodiment of the present invention. Referring to Figs. 4 and 5, reference numeral 1 denotes a transparent sealed container, and more preferably, a glass bulb. Incident window 2 on which a plurality of light beams to be measured are incident are formed at one end face of the glass bulb 1. A plurality of transmission type photoelectric surfaces 3 are formed on the inner surface of the incident window 2 and aligned one-dimensionally, i.e., in one array. One set of a dynode array 6 for receiving photoelectrons from the corresponding photoelectric surface 3 and multiplying them by the secondary electron emission effect is provided inside the glass bulb 1 for each photoelectric surface 3. The photoelectron incident ports of first-stage dynodes  $7_1$  of the respective dynode arrays 6 are arranged to oppose the photoelectric surface 3 and are thus aligned in a one-dimensional array. One focusing electrode 4 is arranged between the photoelectric surfaces 3 and the dynode arrays 6, and openings 5 serving as the inlet ports of the photoelectrons are formed at portions of the focusing electrode 4 adjacent to dynodes  $7_1$ . An anode 8 is arranged in front of a last-stage dynode  $7_L$  of each dynode array 6 to collect secondary electrons emitted from this last-stage dynode  $7_L$ . In Figs. 4 and 5, reference numerals 9 denote mesh electrodes. The mesh electrodes 9 reliably guide the photoelectrons incident through the openings 5 of the focusing electrode 4 to the corresponding first-stage dynodes  $7_1$  without flowing them in the opposite direction.

The dynode arrays 6 used in this embodiment have in-line dynode structure and all of them have the same arrangement. The dynodes 7 of each dynode array 6 are arranged in the staggered manner along the direction of the incident light beam to be measured such that the recessed surfaces (secondary electron emission surfaces) of their arcuated wall portions oppose each other. The dynodes 7 located on the same stage are supported by one conductive support plate 10 and the same voltage is applied to the dynodes 7 on the same stage by a bleeder resistor (not shown).

According to the present invention, the adjacent dynode arrays 6 are directed alternately in the opposite directions. More specifically, as shown in Fig. 6, when the direction of secondary electron emission of the first-stage dynode 7<sub>1</sub> of one dynode array 6a is set in the +X direction, the direction of secondary electron emission of the first-stage dynode 7<sub>1</sub> of a dynode array 6b adjacent to the dynode array 6a is set in an opposite direction at 180° (-X direction). Then, the dynode array 6a is arranged at a predetermined distance from the adjacent dynode array 6b in the +X direction. This arrangement applies to other dynode arrays 6.

The operation of the photomultiplier having the above arrangement according to the present invention will be described.

When a plurality of light beams to be measured are incident on the incident window 2 of the glass bulb 1, the respective light beams to be measured are converted to photoelectrons by the corresponding photoelectric surfaces 3. The photoelectrons are incident on the first-stage dynodes 7<sub>1</sub> of the corresponding dynode arrays 6 through the openings 5 of the focusing electrode 4, and bombarded on the secondary electron emission surfaces of the first-stage dynodes 7<sub>1</sub>, thereby emitting secondary electrons. The secondary electrons are further sequentially multiplied by the dynodes 7 from the second stages, finally collected by the anodes 8, and output to the outside of the photomultiplier as output signals.

The dynode array 6a in Fig. 6 will be considered. While the secondary electrons are transmitted in the dynode array 6a, some of them leak from the gap among the dynodes 7 in the lateral direction (+Y direction in Fig. 6). However, the dynode array 6b adjacent to this dynode array 6a is shifted from the dynode array 6a in the -X direction, and the gaps among the dynodes 7 of the dynode array 6b are remote from those of the dynode array 6a. Therefore, the leaking electrons from the dynode array 6a will not mix in the adjacent dynode array 6b, so that occurrence of crosstalk is prevented. Accordingly, the respective dynode arrays 6 have excellent separation and independency. The detection result of the light beam to be measured incident on each photoelectric surface 3 has high precision which is not adversely affected by other light beams to be measured.

The following Table 1 indicates the rate of occurrence of crosstalk in the conventional 6-channel photomultiplier shown in Figs. 1 and 2.

Table 1

Light Beam To Be Measured Incident Channel	1 CH	2 CH	3 CH	4 CH	5 CH	6 CH
Output Channel						
1 CH	-	0.21%				
2 CH	0.24%	-	0.22%			
3 CH		0.24%	-	0.22%		
4 CH			0.27%	-	0.20%	
5 CH				0.24%	-	0.39%
6 CH					0.17%	-

Table 2 indicates the rate of occurrence of crosstalk in the 6-channel photomultiplier of the same type as that shown in Figs. 4 and 5.

Table 2

5	Light Beam To Be Measured Incident Channel	1 CH	2 CH	3 CH	4 CH	5 CH	6 CH
	Output Channel						
	1 CH		0.04%				
	2 CH	0.09%		0.03%			
10	3 CH		0.10%		0.07%		
	4 CH			0.04%		0.03%	
	5 CH				0.05%		0.08%
15	6 CH					0.02%	

From Tables 1 and 2, it is apparent that crosstalk is largely decreased by adopting the arrangement of the present invention.

#### 20 (Embodiment 2)

Although the dynode arrays 6 used in the photomultiplier of the above embodiment have in-line dynode structure, the present invention is not limited to them. For example, in dynode arrays 16 of a photomultiplier shown in Fig. 7, dynodes on the first and second stages use cylindrical quarter dynodes 17<sub>1</sub> and 17<sub>2</sub>, and dynodes on the third stage and so on have venetian-blind structure. Except for that, the constituent elements are the same as in the above embodiment. Thus, they are denoted by the same reference numerals, and a detailed description thereof will be omitted. As is apparent from Fig. 7, the adjacent dynode arrays 16 are shifted from each other, and leaking electrons in the horizontal direction will not mix in the adjacent dynode array 16.

#### 30 (Embodiment 3)

Fig. 8 shows a photomultiplier according to the present invention in which dynode arrays 26 have venetian-blind structure in all the stages. In these dynode arrays 26, unlike in the embodiment described above, even the secondary electron emission direction of second-stage dynodes 27<sub>2</sub> is set the same as that of first-stage dynodes 27<sub>1</sub>, as is clearly seen in Fig. 9. Accordingly, the distance between adjacent dynode arrays 26a and 26b is further increased, thereby further improving the effect of preventing mixing of leaking electrons.

All the above various embodiments are related to transmission type photomultipliers. However, the present invention can similarly be applied to a reflection type photomultiplier.

#### 40 (Embodiment 4)

Fig. 10 shows a reflection type photomultiplier according to an embodiment of the present invention. Although the basic arrangement of this photomultiplier is close to that of the transmission type photomultiplier, this photomultiplier has neither photoelectric surfaces on the inner surface of incident window 2 of its glass bulb 1 nor a focusing electrode. Referring to Fig. 10, reference numerals 30 denote cylindrical quarter photocathodes. Reflection type photoelectric surfaces 31 are formed on the recessed surfaces of the photocathodes 30. Light beams to be measured incident through the incident window 2 passes through a mesh electrode 9 and are bombarded on the photoelectric surfaces 31 of the photocathodes 30 to generate photoelectrons. The photoelectrons are guided to dynode arrays 36 having proximity mesh dynode structure, multiplied by the secondary electron emission effect, and captured by anodes 8.

Although the light beam incident ports of the photoelectric surfaces 31 are aligned one-dimensionally, the photoelectron emission directions of the adjacent light beam incident ports are set in opposite directions at 180° from each other. Accordingly, a dynode array 36 connected to a certain photocathode 30 is set in the opposite direction alternately from the adjacent dynode array 36, so that crosstalk between the dynode arrays 36 is prevented in the same manner as in the above transmission type photomultiplier.

## (Embodiment 5)

This reflection type photomultiplier has various types, and Fig. 11 shows an example. In a reflection type photomultiplier shown in Fig. 11, photocathodes 40 having reflection type photoelectric surfaces 41 and first-stage dynodes 47, of dynode arrays 46 have venetian-blind structure, and the dynodes from the second stage of the dynode arrays 46 have proximity mesh dynode structure. The photoelectron emission direction of the photoelectric surface 41 of one photocathode 40 is set in the opposite direction at 180° from that of the adjacent one, and the positions of the adjacent dynode arrays 46 are shifted from each other, which will be readily understood from Fig. 11.

## (Embodiment 6)

Fig. 12 shows a linear multi-anode electron multiplier for detecting the energy beams of electrons, ions and so force. The electron multiplier corresponds to an arrangement obtained by removing a glass bulb, photoelectric surfaces, and a focusing electrode 4 from a transmission type photomultiplier. The electron multiplier of the embodiment shown in Fig. 12 has a plurality dynode arrays 56 having box-and-grid dynode structure, and the energy beam incident ports of first-stage dynodes 57, of the dynode arrays 56 are aligned one-dimensionally. The present invention is applicable to this electron photomultiplier as well. The direction of secondary electron emission of the first-stage dynode 57, of each dynode array 56 is set in the opposite direction at 180° from that of first-stage dynode 57, of an adjacent dynode array 56. Accordingly, when the energy beams of electrons are incident on the energy beam incident ports of the first-stage dynodes 57, the electrons leaking from the gaps among dynodes 57 will not mix in the adjacent dynode array 56 in completely the same manner as in the function at the diode arrays 6 of the above-mentioned photomultiplier. The electrons multiplied in the dynode arrays 56 are finally captured by anodes 8. In Fig. 12, reference numerals 60 denote bleeder resistors.

More details of photomultiplier itself and the dynode structure used therefor are disclosed in Photomultiplier Handbook by RCA Corporation printed in USA.

From the invention thus described, it will be obvious that the invention may be varied in many ways. Such variations are not to be regarded as a departure from the spirit and scope of the invention, and all such modifications as would be obvious to one skilled in the art are intended to be included within the scope of the following claims.

## Claims

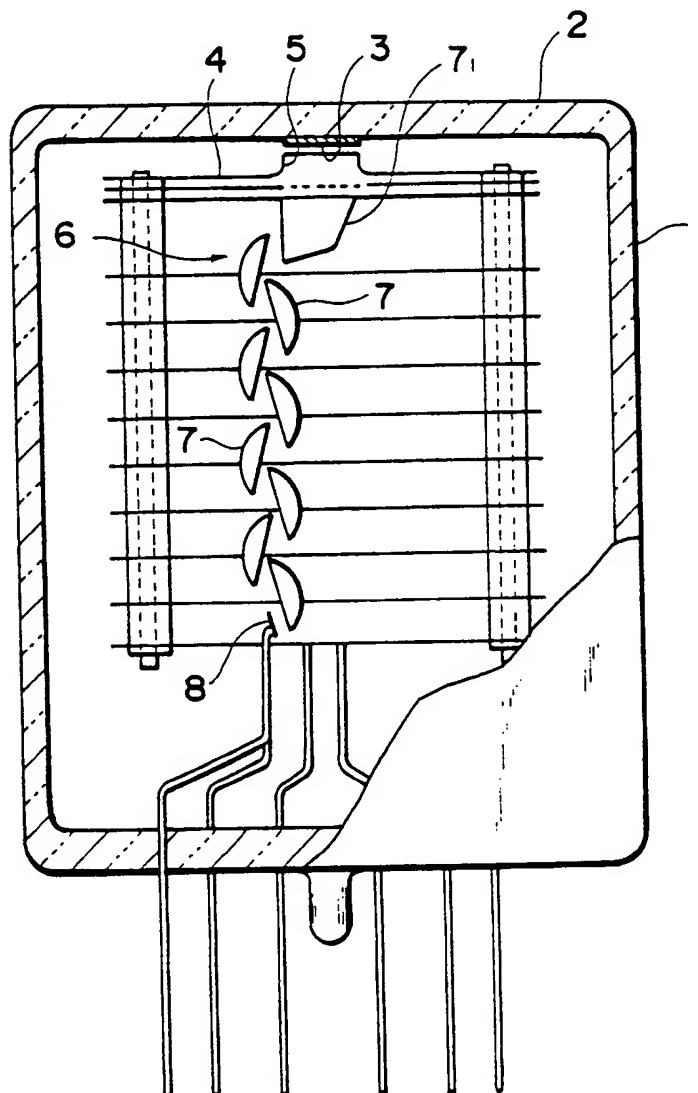
1. A photomultiplier comprising:
  - a transparent sealed container having, on one end face thereof, incident window on which light to be measured is incident;
  - first and second transmission type photoelectric surfaces formed on an inner surface of said incident window; and
  - first and second dynode arrays having a plurality of stages of dynodes for multiplying photoelectrons supplied from said first and second transmission type photoelectric surfaces respectively, photoelectron incident ports of first-stage dynodes of said first and second dynode arrays opposing said first and second transmission type photoelectric surfaces respectively,
  - wherein said dynodes of said first and second dynode arrays are arranged such that electrons leaking from said first dynode array will not enter said second dynode array.
2. A photomultiplier according to claim 1, wherein said dynodes of said first and second dynode arrays are arranged such that a direction of secondary electron emission of one stage dynode of said first dynode array is different from that of the same stage dynode of said second dynode array.
3. A photomultiplier according to claim 1, wherein said first and second transmission type photoelectric surfaces are aligned adjacent to each other, and said dynodes of said first and second dynode arrays are arranged to be shifted from each other in a direction perpendicular to a direction along which said first and second transmission type photoelectric surfaces are aligned.
4. A photomultiplier according to claim 3, wherein said first and second dynode arrays are identical, and said first dynode array is arranged in a direction rotated through 180° from said second dynode array about an axis perpendicular to said first transmission type photoelectric surface.

5. A photomultiplier according to claim 1, wherein said first and second dynode arrays have in-line dynode structure.
6. A photomultiplier according to claim 1, wherein said first and second dynode arrays have venetian-blind dynode structure.
7. A photomultiplier according to claim 6, wherein directions of secondary electron emission of said first-stage dynodes of said first and second dynode arrays are opposite to each other, directions of secondary electron emission of said first- and second-stage dynodes of said first dynode array are the same, and directions of secondary electron emission of said first- and second-stage dynodes of said second dynode array are the same.
8. A photomultiplier according to claim 1, wherein said first and second dynode arrays have proximity mesh dynode structure.
9. A photomultiplier according to claim 1, wherein said first and second dynode arrays have box-and-grid dynode structure.
10. A photomultiplier comprising:
  - a transparent sealed container having, on one end face thereof, incident window on which light to be measured is incident;
  - first and second reflection type photoelectric surfaces arranged in said sealed container and having light beam incident ports arranged to oppose said incident window; and
  - first and second dynode arrays having a plurality of stages of dynodes for multiplying photoelectrons supplied from said first and second reflection type photoelectric surfaces respectively, said first and second dynode arrays being provided to correspond to said first and second reflection type photoelectric surfaces,
  - wherein said dynodes of said first and second dynode arrays are arranged such that electrons leaking from said first dynode array will not enter said second dynode array.
11. A photomultiplier according to claim 10, wherein said dynodes of said first and second dynode arrays are arranged such that a direction of secondary electron emission of one stage dynode of said first dynode array is different from that of the same stage dynode of said second dynode array.
12. A photomultiplier according to claim 10, wherein said first and second reflection type photoelectric surfaces are aligned adjacent to each other, and said dynodes of said first and second dynode arrays are arranged to be shifted from each other in a direction perpendicular to a direction along which said first and second reflection type photoelectric surfaces are aligned.
13. A photomultiplier according to claim 12, wherein said first and second dynode arrays are identical, and said first dynode array is arranged in a direction rotated through 180° from said second dynode array about an axis perpendicular to said first reflection type photoelectric surface.
14. A photomultiplier according to claim 10, wherein said first and second dynode arrays have in-line dynode structure.
15. A photomultiplier according to claim 10, wherein said first and second dynode arrays have venetian-blind dynode structure.
16. A photomultiplier according to claim 15, wherein directions of secondary electron emission of said first-stage dynodes of said first and second dynode arrays are opposite to each other, directions of secondary electron emission of said first- and second-stage dynodes of said first dynode array are the same, and directions of secondary electron emission of said first- and second-stage dynodes of said second dynode array are the same.
17. A photomultiplier according to claim 10, wherein said first and second dynode arrays have proximity mesh dynode structure.
18. A photomultiplier according to claim 10, wherein said first and second dynode arrays have box-and grid dynode structure.

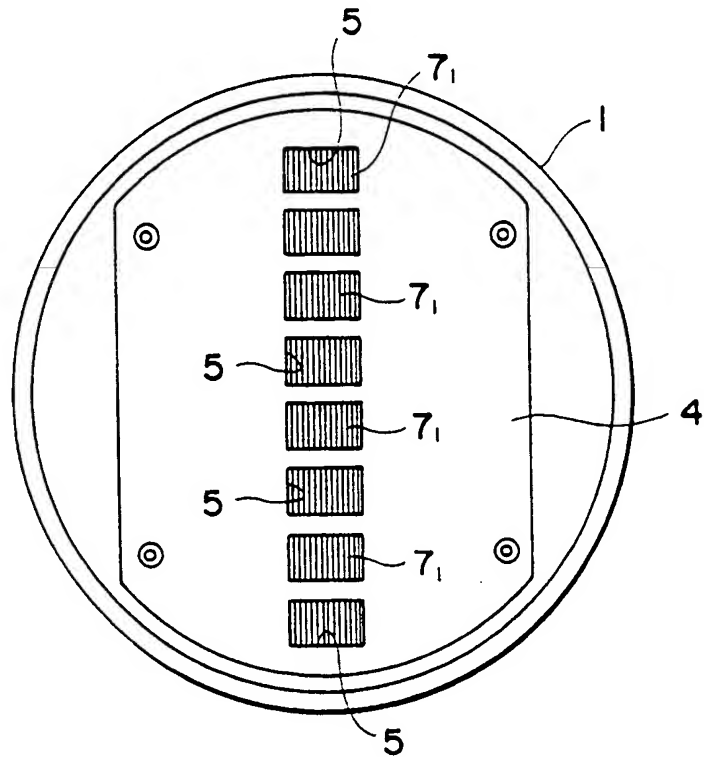
19. An electron multiplier comprising first and second dynode arrays having a plurality of stages of dynodes for multiplying electrons generated when energy beams of electrons, ions and so force are incident thereon, said plurality of stages of dynodes including first-stage dynodes arranged such that energy beam incident ports thereof are directed in a direction along which said energy beams are incident,  
5        wherein said dynodes of said first and second dynode arrays are arranged such that electrons leaking from said first dynode array will not enter said second dynode array.
20. An electron multiplier according to claim 19, wherein said dynodes of said first and second dynode arrays are arranged such that a direction of secondary electron emission of one stage dynode of said first dynode array is different from that of the same stage dynode of said second dynode array.  
10
21. An electron multiplier according to claim 19, wherein said energy beam incident ports of said first and second dynode arrays are aligned adjacent to each other, and said dynodes of said first and second dynode arrays are arranged to be shifted from each other in a direction perpendicular to a direction along which said energy beam incident ports are aligned.  
15
22. An electron multiplier according to claim 21, wherein said first and second dynode arrays are identical, and said first dynode array is arranged in a direction rotated through 180° from said second dynode array about an axis substantially coinciding with the direction along which said energy beams are incident.
23. An electron multiplier according to claim 19, wherein said first and second dynode arrays have in-line dynode structure.  
20
24. An electron multiplier according to claim 19, wherein said first and second dynode arrays have venetian-blind dynode structure.  
25
25. An electron multiplier according to claim 24, wherein directions of secondary electron emission of said first-stage dynodes of said first and second dynode arrays are opposite to each other, directions of secondary electron emission of said first- and second-stage dynodes of said first dynode array are the same, and directions of secondary electron emission of said first- and second-stage dynodes of said second dynode array are the same.  
30
26. An electron multiplier according to claim 19, wherein said first and second dynode arrays have proximity mesh dynode structure.
27. An electron multiplier according to claim 19, wherein said first and second dynode arrays have box-and-grid dynode structure.  
35
28. A photomultiplier or electron multiplier comprising two sequences of dynodes arranged to multiply electrons resulting from two respective incident beams, the arrangement being such that electrons leaking from one of the two sequences of dynodes will not enter the other sequence of dynodes.  
40
- 45
- 50
- 55



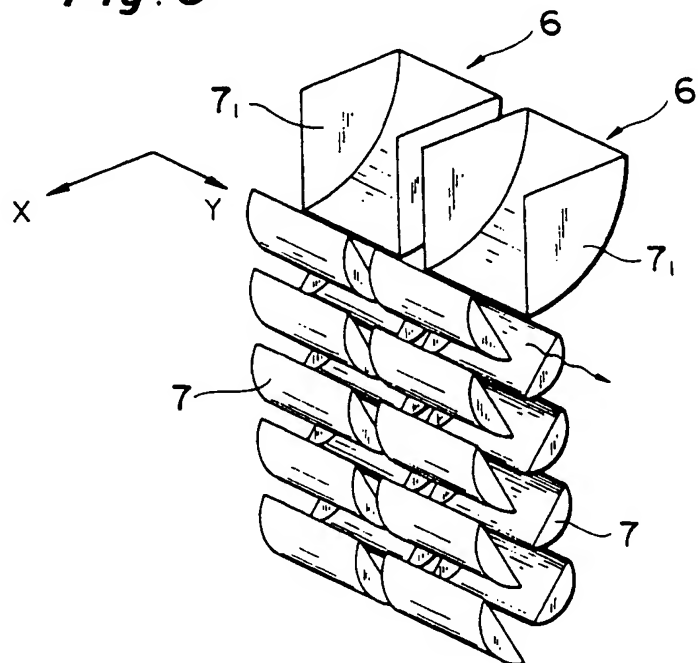
*Fig. 1*



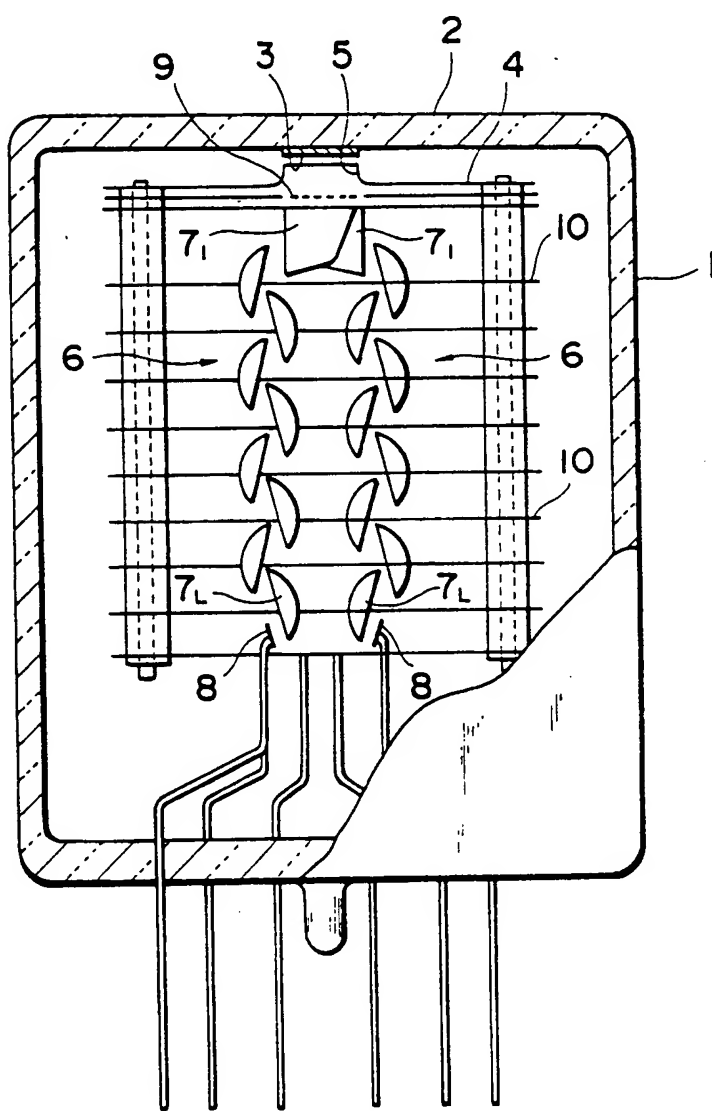
*Fig. 2*



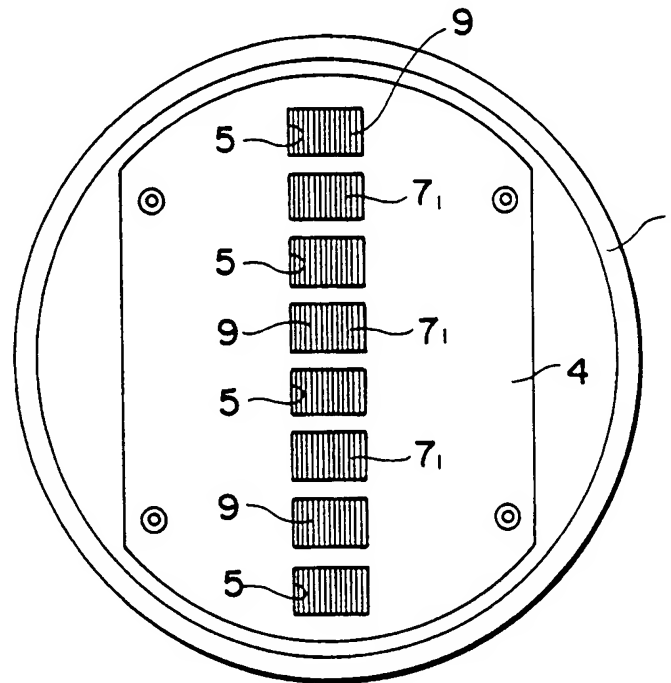
*Fig. 3*



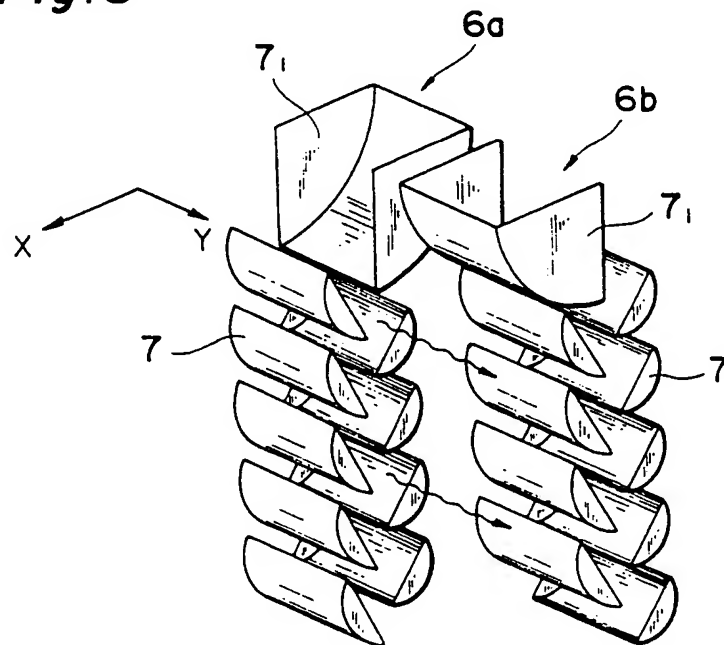
**Fig. 4**



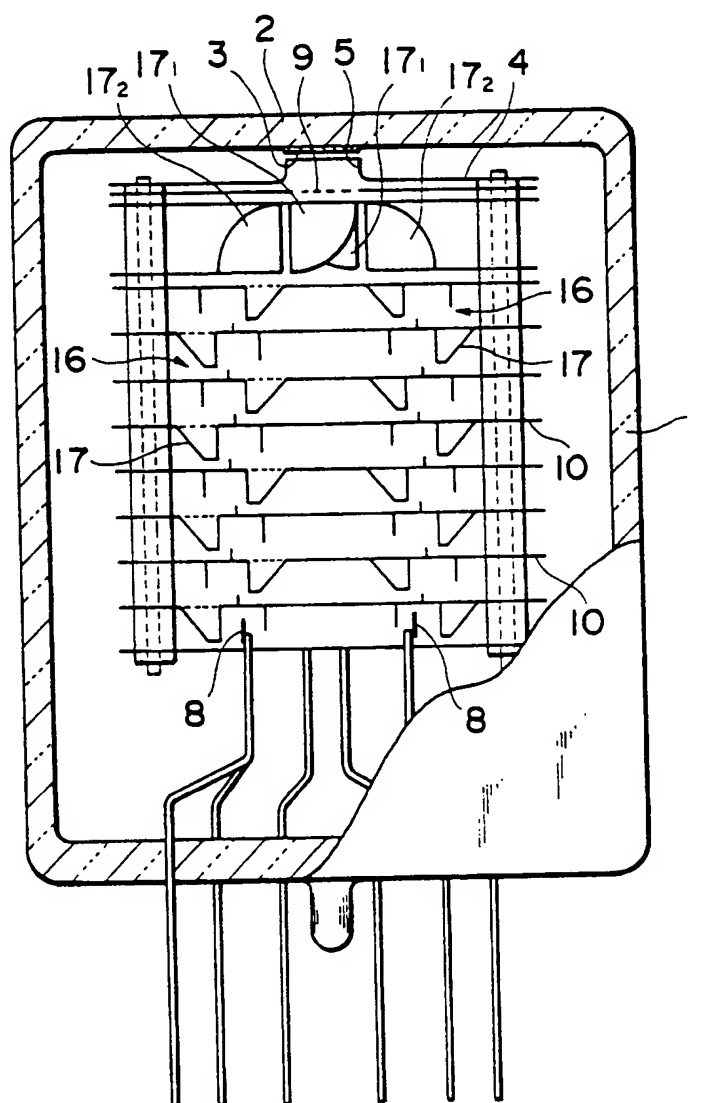
*Fig. 5*



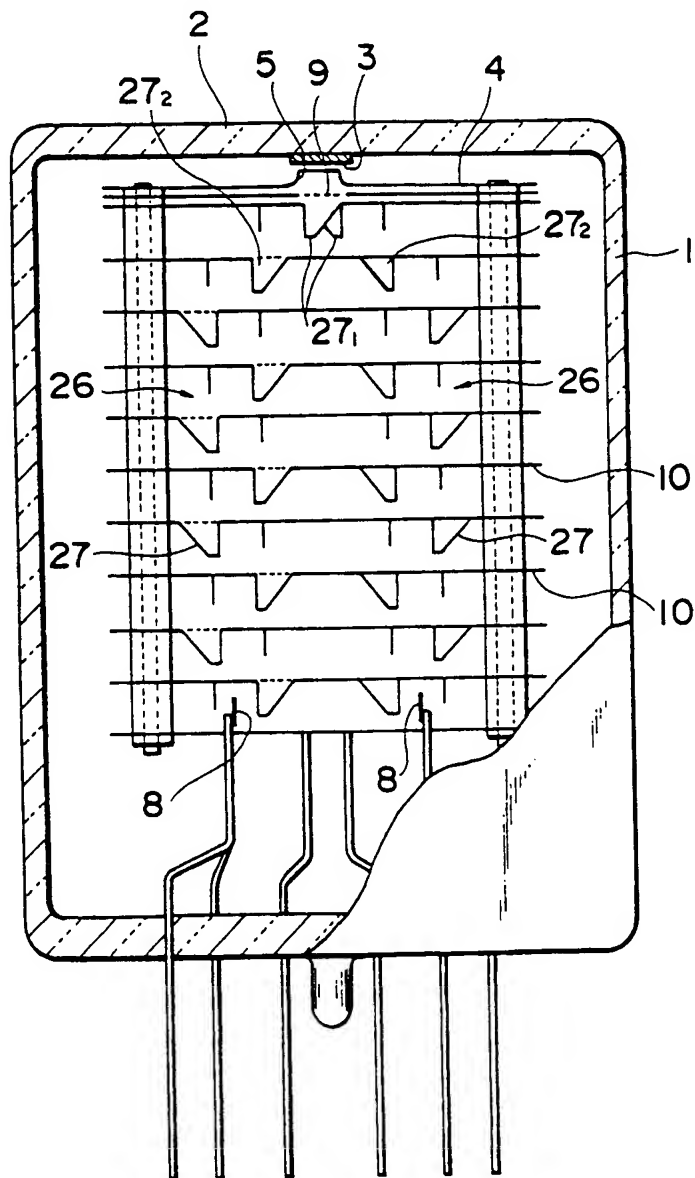
*Fig. 6*



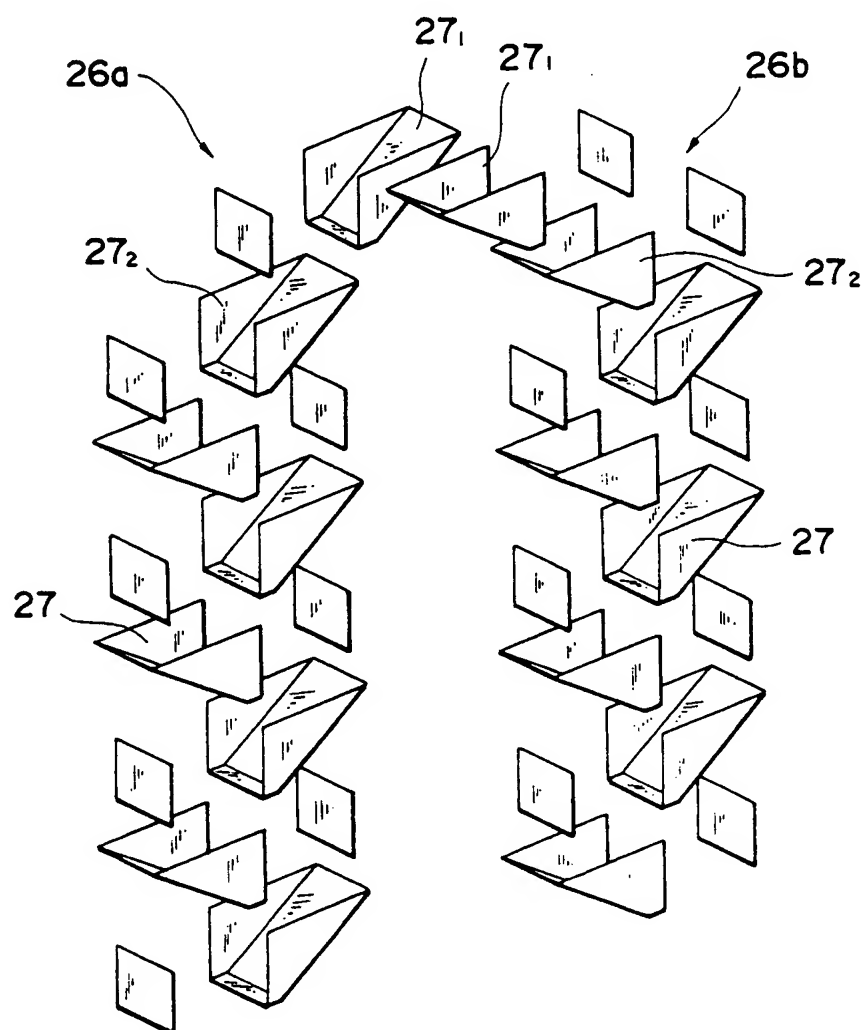
**Fig. 7**



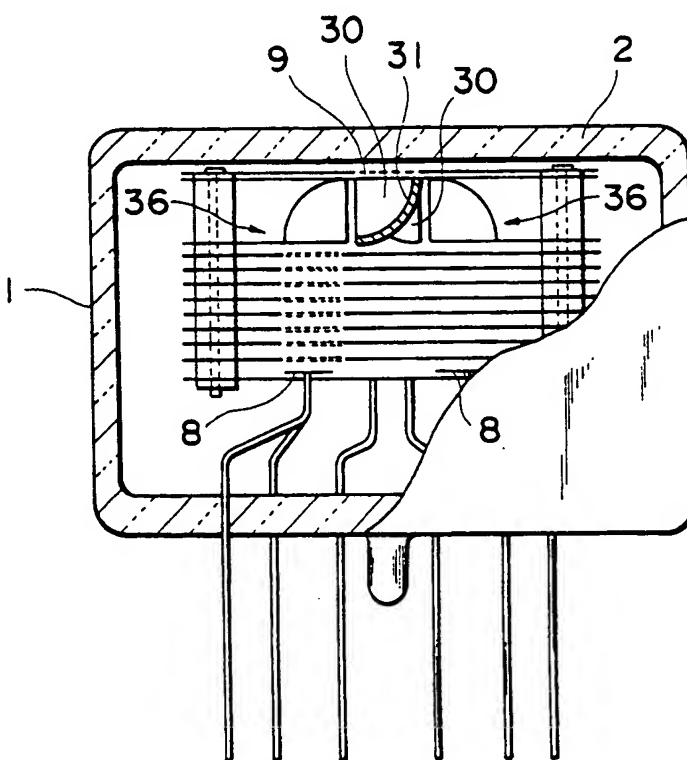
*Fig. 8*



*Fig. 9*

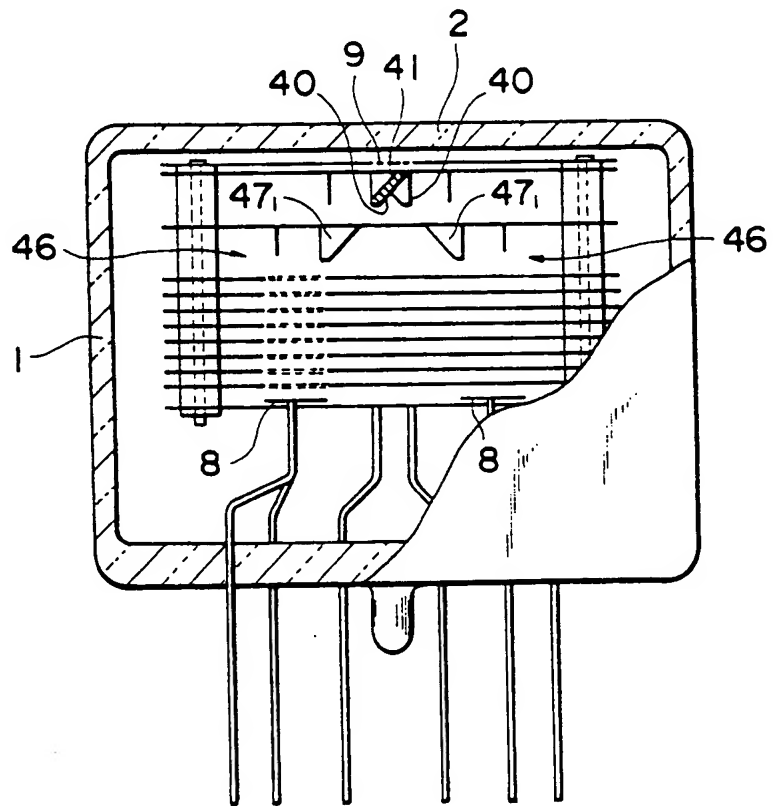


*Fig. 10*

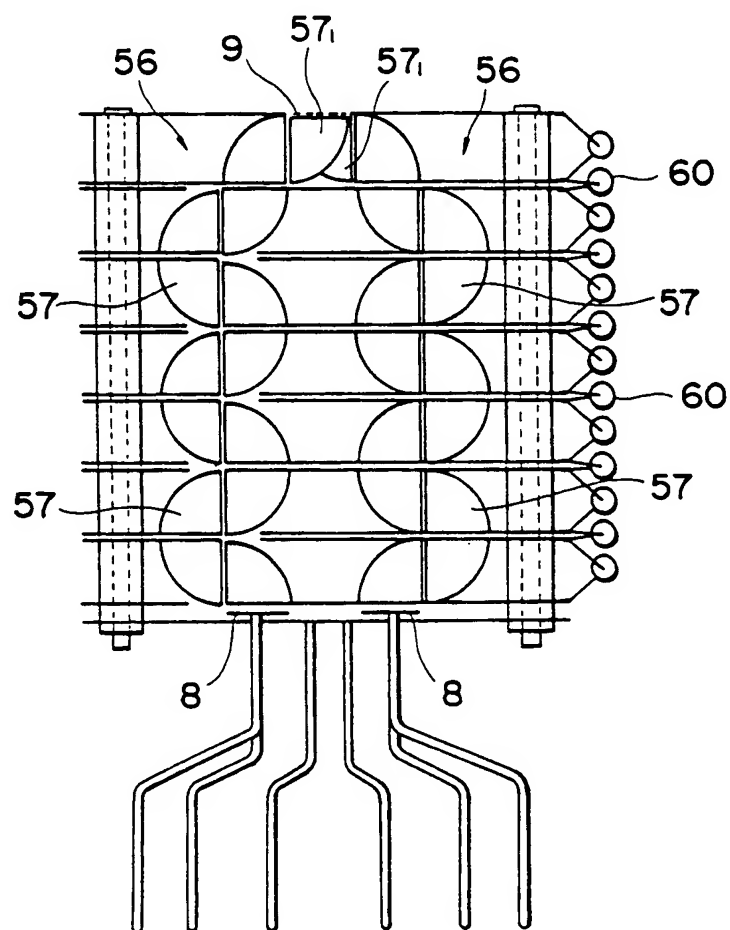




*Fig. 11*



*Fig. 12*





European Patent  
Office

# EUROPEAN SEARCH REPORT

Application Number  
EP 93 30 8931

DOCUMENTS CONSIDERED TO BE RELEVANT			
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.Cl.5)
A	US-A-5 077 504 (HELVY) * claims 1-6 * * column 1, line 53 - line 63; figures 1,2 * column 3, line 46 - line 68 * ---	1,5,14, 23,28	H01J43/04 H01J43/18
A	EP-A-0 427 545 (HAMAMATSU PHOTONICS) * claim 1 * * column 5, line 53 - column 6, line 23 * * column 7, line 17 - line 38; figures 1-3 ---	1,6,15, 24,28	
A	US-A-4 825 118 (KYUSHIMA) * claim 1 * * column 4, line 55 - column 5, line 53; figure 5 * ---	19,28	
A	PATENT ABSTRACTS OF JAPAN vol. 9, no. 19 (E-292)(1742) 25 January 1985 & JP-A-59 167 946 (HAMAMATSU) 21 September 1984 * abstract * -----	8,9,17, 18,26,27	TECHNICAL FIELDS SEARCHED (Int.Cl.5) H01J
The present search report has been drawn up for all claims			
Place of search THE HAGUE		Date of completion of the search 24 January 1994	Examiner Greiser, N
CATEGORY OF CITED DOCUMENTS X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document		T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons ..... & : member of the same patent family, corresponding document	

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